

Times - New Trends in Materials Science and Engineering 1st International Virtual Conference



ariable angle spectroscopic llipsometry characterization of educed graphene oxide stabilized ith poly(sodium 4-styrenesulfonate)

<u>Grazia Giuseppina Politano¹</u>, Carlo Vena¹, Giovanni Desiderio ², Carlo Versace^{1,2} 1. Department of Physics, University of Calabria 87036 Rende CS, Italy 2. CNR-NANOTEC, 87036 Rende CS, Italy

Abstract

Lately, the optical properties of Graphene Oxide (GO) and Reduced Graphene Oxide (RGO) films have been studied in the ultraviolet and visible spectral range. However, the accurate optical properties in the extended near-infrared and mid-infrared range have not been investigated yet. In this contribution, we report a Variable Angle Spectroscopic Ellipsometry (VASE) characterization of GO thin films dip-coated on SiO₂/Si substrates and thermally reduced GO films in the 0.38-4.1 eV photon energy range, i.e. from the near-infrared up to ultraviolet range of the electromagnetic spectrum. Moreover, we explore the optical properties of RGO stabilized with poly(sodium 4-styrenesulfonate) (PSS) films dip-coated on SiO₂/Si substrates. Definitely, the Lorentz optical models fit well the experimental data. Correspondingly, the morphological properties of all studied samples were characterized by Scanning Electron Microscopy (SEM).

Methods and materials

- \succ Dip-coating process was employed to deposit GO and PSS-functionalized RGO on SiO₂/Si (SiO₂ \sim 2 nm) substrates
- The samples were prepared using commercial dispersions in H₂O of GO (4 mg/mL) and PSS-functionalized RGO (10 mg/mL). The solutions were sonicated for 30 minutes using an ultrasonic bath.
- > GO films on SiO₂/Si were eventually heated at 400 °C for 20 min in an Ar atmosphere furnace.
- The optical characterization of the samples was carried out by using VASE. Spectra of the ellipsometric angles ψ and Δ were acquired using a V-Vase (Woollam) Co.) ellipsometer in the [0.38 -4.1] eV photon energy range at 65°, 70°, 75° incident angles at room temperature.

SEM measurements



Figure 1. SEM images of (a) graphene oxide films on SiO₂/Si substrates and (b) the related magnification



Figure 2. SEM images of (a) thermally reduced graphene oxide films on SiO₂/Si substrates and (b) the related magnification



Figure 3. Scanning Electron Microscopy image of (a) reduced graphene oxide films stabilized with PSS on SiO₂/Si substrates and (b) the related magnification.

CONTACT PERSON

- Grazia Giuseppina Politano Università della Calabria Dipartimento di Fisica Email:grazia.politano@unical.it
- REFERENCES
- 1. G. G. Politano et al. Coatings 10 (2020) 743
- 2. G. Eda et al. Adv. Mater. 22 (2010) 505-509
- 3. H. F. Liang et al. J. Mater. Chem. C. 3 (2015) 12484-12491



Figure 4. Estimated dispersion laws of (a) graphene oxide and (b) thermally reduced graphene oxide films on SiO₂/Si substrates by ellipsometry characterization

- Dispersion laws of GO and thermally reduced GO films are described by three Lorentz oscillators [1].
- In GO optical model, oscillator 1 at ~ 2.8 eV denotes different coverage of mixed hydroxyl groups and oxygen atoms. Oscillator 2 at ~ 3.2 eV (at ~ 388 nm) represents a transition that is near the shoulder in the absorbance spectrum of GO (at~ 320 nm) and close to the wavelength of blue luminescence detected for partially RGO (at \sim 390 nm). Oscillator 3 at \sim 3.9 eV is assigned to the small shoulder of GO in absorbance spectrum.
- In RGO optical model, oscillator 1 at ~ 2.1 eV denotes different coverage of mixed hydroxyl groups and oxygen atoms. Oscillator 2 at \sim 3.17 eV is related to the narrow photoluminescence peak observed for partially RGO. Oscillator 3 at ~ 4 eV falls in the range of blue photoluminescence [2].



Figure 5. Dispersion laws of reduced GO stabilized with poly(sodium 4-styrenesulfonate) on SiO₂/Si substrates

14-18 June 2021

- The dispersion laws of PSSfunctionalized RGO on SiO₂/Si are described by a Lorentz oscillator and a pole [1].
- In PSS-RGO optical model, oscillator 1 at ~ 2.8 eV is assigned to states originated by sp² hydridization in the rearrangement due to reduction [3]. Oscillator 2 is outside the ellipsometer's range and the pole function covers its contribution.

